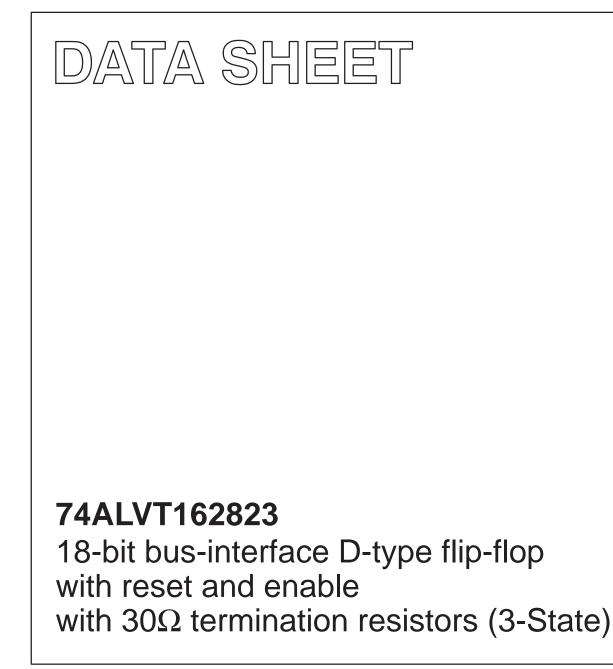
INTEGRATED CIRCUITS



Product specification IC24 Data Handbook 1998 Aug 27

PHILIPS



74ALVT162823

FEATURES

- Two sets of high speed parallel registers with positive edge-triggered D-type flip-flops
- 5V I/O Compatible
- Ideal where high speed, light loading, or increased fan-in are required with MOS microprocessors
- Live insertion/extraction permitted
- Power-up 3-State
- Power-up Reset
- Output capability: +12mA/-12mA
- Latch-up protection exceeds 500mA per Jedec Std 17
- ESD protection exceeds 2000 V per MIL STD 883 Method 3015 and 200 V per Machine Model
- Bus hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Outputs include series resistance of 30Ω making external termination resistors unnecessary

DESCRIPTION

The 74ALVT162823 18-bit bus interface register is designed to eliminate the extra packages required to buffer existing registers and provide extra data width for wider data/address paths of buses carrying parity.

The 74ALVT162823 has two 9-bit wide buffered registers with Clock Enable (n \overline{CE}) and Master Reset (n \overline{MR}) which are ideal for parity bus interfacing in high microprogrammed systems.

The registers are fully edge-triggered. The state of each D input, one set-up time before the Low-to-High clock transition is transferred to the corresponding flip-flop's Q output.

The 74ALVT162823 is designed with 30Ω series resistance in both the pull-up and pull-down output structures. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus receivers/transmitters.

SYMPOL	DADAMETER	CONDITIONS	TYPI	UNIT	
STMBOL	SYMBOLPARAMETERConstructionTamb = 25°C; GND = 0V		2.5V	3.3V	UNIT
t _{PLH} t _{PHL}	Propagation delay nCP to nQx	C _L = 50pF	4.2 3.4	3.0 2.8	ns
C _{IN}	Input capacitance	$V_I = 0V \text{ or } V_{CC}$	3	3	pF
C _{OUT}	Output capacitance	$V_{I/O} = 0V \text{ or } 3.0V$	9	9	pF
I _{CCZ}	Total supply current	Outputs disabled	40	70	μA

ORDERING INFORMATION

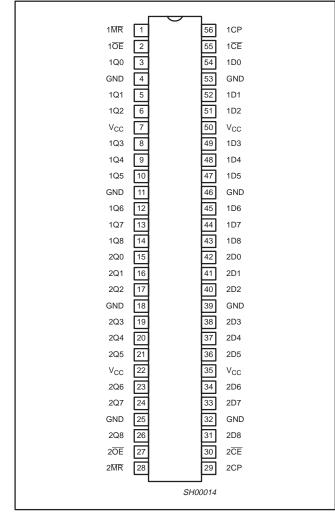
PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
56-Pin Plastic SSOP Type III	–40°C to +85°C	74ALVT162823 DL	AV162823 DL	SOT371-1
56-Pin Plastic TSSOP Type II	–40°C to +85°C	74ALVT162823 DGG	AV162823 DGG	SOT364-1

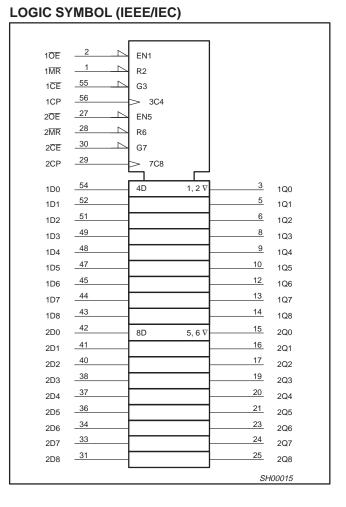
PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
2, 27	10E, 20E	Output enable input (active-Low)
54, 52, 51, 49, 48, 47, 45, 44, 43 42, 41, 40, 38, 37, 36, 34, 33, 31	1D0-1D8 2D0-2D8	Data inputs
3, 5, 6, 8, 9, 10, 12, 13, 14 15, 16, 17, 19, 20, 21, 23, 24, 26	1Q0-1Q8 2Q0-2Q8	Data outputs
56, 29	1CP, 2CP	Clock pulse input (active rising edge)
55, 30	1CE, 2CE	Clock enable input (active-Low)
1, 28	1 <u>MR</u> , 2 <u>MR</u>	Master reset input (active-Low)
4, 11, 18, 25, 32, 39, 46, 53	GND	Ground (0V)
7, 22, 35, 50	V _{CC}	Positive supply voltage

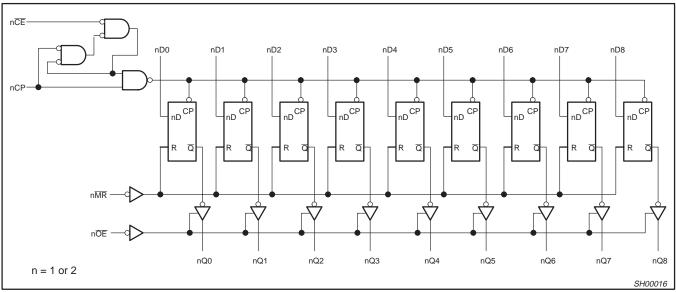
74ALVT162823

PIN CONFIGURATION





LOGIC DIAGRAM



74ALVT162823

FUNCTION TABLE

INPUTS					OUTPUTS	OPERATING MODE
nOE	nMR	nCE	nCP	nDx	nQ0 – nQ8	OFERATING MODE
L	L	Х	Х	Х	L	Clear
L	Н	L	Ŷ	h	Н	Load and read data
L	Н	L	Ŷ	I	L	Load and read data
L	Н	Н	¢	Х	NC	Hold
Н	Х	Х	Х	Х	Z	High impedance

H = High voltage level

h = High voltage level one set-up time prior to the Low-to-High clock transition

L = Low voltage level

= Low voltage level one set-up time prior to the Low-to-High clock transition

NC= No change

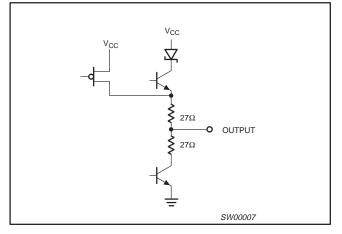
X = Don't care

Z = High impedance "off" state

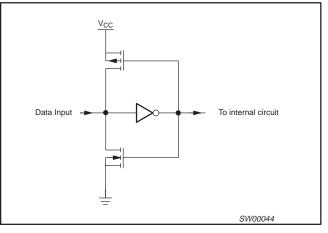
 \uparrow = Low to High clock transition

 \uparrow = Not a Low-to-High clock transition

SCHEMATIC OF EACH OUTPUT



BUS HOLD CIRCUIT



ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V ₁ < 0	-50	mA
VI	DC input voltage ³		-0.5 to +7.0	V
I _{OK}	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V
	DC output current	Output in Low state	128	
IOUT		Output in High state	-64	- mA
T _{stg}	Storage temperature range		-65 to +150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	2.5V RAN	2.5V RANGE LIMITS		3.3V RANGE LIMITS		
	FARAMETER	MIN	MAX	MIN	MAX	UNIT	
V _{CC}	DC supply voltage	2.3	2.7	3.0	3.6	V	
VI	Input voltage	0	5.5	0	5.5	V	
VIH	High-level input voltage	1.7		2.0		V	
V _{IL}	Input voltage		0.7		0.8	V	
I _{ОН}	High-level output current		-8		-12	mA	
I _{OL}	Low-level output current		12		12	mA	
$\Delta t / \Delta v$	Input transition rise or fall rate; Outputs enabled		10		10	ns/V	
T _{amb}	Operating free-air temperature range	-40	+85	-40	+85	°C	

DC ELECTRICAL CHARACTERISTICS (3.3V ± 0.3V RANGE)

					LIMITS		
SYMBOL	IBOL PARAMETER TEST CONDITIONS		TEST CONDITIONS		Temp = -40°C to +85°C		UNIT
				MIN	TYP ¹	MAX	1
V _{IK}	Input clamp voltage	$V_{CC} = 3.0V; I_{IK} = -18mA$			-0.85	-1.2	V
V _{OH}	High-level output voltage	V _{CC} = 3.0V; I _{OH} = -12mA		2.0	2.3		V
V _{OL}	Low-level output voltage	$V_{CC} = 3.0V; I_{OL} = 12mA$			0.5	0.8	V
V _{RST}	Power-up output low voltage ⁶	$V_{CC} = 3.6V$; $I_O = 1mA$; $V_I = V_{CC}$ or GND				0.55	V
		$V_{CC} = 3.6V; V_I = V_{CC} \text{ or GND}$	Control nino		0.1	±1	μA
		$V_{CC} = 0 \text{ or } 3.6 \text{V}; \text{ V}_{\text{I}} = 5.5 \text{V}$	Control pins		0.1	10	1
I _I	Input leakage current	$V_{CC} = 3.6V; V_{I} = 5.5V$			0.1	10	μA
		$V_{CC} = 3.6V; V_I = V_{CC}$	Data pins ⁴		0.5	1	
		$V_{CC} = 3.6V; V_I = 0$			0.1	-5	1
I _{OFF}	Off current	$V_{CC} = 0V; V_{I} \text{ or } V_{O} = 0 \text{ to } 4.5V$	<u>-</u>		0.1	±100	μA
	Bus Hold current	$V_{CC} = 3V; V_I = 0.8V$		75	130		
I _{HOLD}	D inputs ⁷	$V_{CC} = 3V; V_{I} = 2.0V$		-75	-140		μA
	D inputs.	$V_{CC} = 0V$ to 3.6V; $V_{CC} = 3.6V$		±500			1
I _{EX}	Current into an output in the High state when $V_O > V_{CC}$	V _O = 5.5V; V _{CC} = 3.0V			10	125	μA
I _{PU/PD}	Power up/down 3-State output current ³	$V_{CC} \le 1.2$ V; $V_O = 0.5$ V to V_{CC} ; $V_I = GND OE/OE = Don't care$) or V _{CC}		1	±100	μA
I _{OZH}	3-State output High current	$V_{CC} = 3.6V; V_{O} = 3.0V; V_{I} = V_{IL} \text{ or } V_{IH}$			0.5	5	μA
I _{OZL}	3-State output Low current	$V_{CC} = 3.6V; V_{O} = 0.5V; V_{I} = V_{IL} \text{ or } V_{IH}$			0.5	-5	μA
ICCH		V_{CC} = 3.6V; Outputs High, V_{I} = GND or V	V _{CC} , I _{O =} 0		0.05	0.1	
I _{CCL}	Quiescent supply current	$V_{CC} = 3.6V$; Outputs Low, $V_I = GND$ or V_{CC} , $I_O = 0$			3.9	5.5	mA
I _{CCZ}	1	$V_{CC} = 3.6V$; Outputs Disabled; $V_I = GND \text{ or } V_{CC} \cdot I_O = 0^5$			0.06	0.1	1
ΔI_{CC}	Additional supply current per input pin ²	$V_{CC} = 3V$ to 3.6V; One input at V_{CC} -0.6V Other inputs at V_{CC} or GND	V,		0.04	0.4	mA

NOTES:

All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.
This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND
This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 3.3V ± 0.3V a transition time of 100µsec is permitted. This parameter is valid for T_{amb} = 25°C only.
Unused pins at V_{CC} or GND.

I_{CCZ} is measured with outputs pulled up to V_{CC} or pulled down to ground.
For valid test results, data must not be loaded into the flip-flops (or latches) after applying power.

7. This is the bus hold overdrive current required to force the input to the opposite logic state.

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AC CHARACTERISTICS (3.3V $\pm\,0.3V$ RANGE)

GND = 0V, $t_R = t_F = 2.5$ ns, $C_L = 50$ pF, $R_L = 500\Omega$

SYMBOL	PARAMETER	WAVEFORM	vo	UNIT		
			MIN	ТҮР	МАХ	1
f _{MAX}	Maximum clock frequency	1				MHz
t _{PLH} t _{PHL}	Propagation delay nCP to nQx	1	1.8 1.8	3.0 2.8	4.7 4.0	ns
t _{PHL}	Propagation delay nMR to nQx	2	1.8	2.8	4.0	ns
t _{PZH} t _{PZL}	Output enable time to High and Low level	4 5	1.9 1.6	3.5 2.6	5.7 3.8	ns
t _{PHZ} t _{PLZ}	Output disable time from High and Low level	4 5	1.9 1.5	3.4 2.5	5.2 3.8	ns

AC SETUP REQUIREMENTS (3.3V \pm 0.3V RANGE)

 $GND = 0V, t_R = t_F = 2.5ns, C_L = 50pF, R_L = 500\Omega$

			LIN	UNIT	
SYMBOL	PARAMETER	WAVEFORM	T _{amb} = -4 V _{CC} = +3		
			MIN	TYP	
t _s (H) t _s (L)	Setup time, High or Low nDx to nCP	3	1.0 1.2	0.6 0.7	ns
t _h (H) t _h (L)	Hold time, High or Low nDx to nCP	3	0.1 0.1	-0.8 -0.6	ns
t _w (H) t _w (L)	nCP pulse width High or Low	1	1.5 2.5	0.7 1.7	ns
t _s (H) t _s (L)	Setup time, High or Low nCE to nCP	3	1.0 0.5	0.2 0.5	ns
t _h (H) t _h (L)	Hold time, High or Low nCE to nCP	3	1.0 1.0	0.5 0.1	ns
t _w (L)	nMR pulse width, Low	2	2.0	1.5	ns
t _{rec}	Recovery time nMR to nCP	2	2.0	1.4	ns

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DC ELECTRICAL CHARACTERISTICS (2.5V ±0.2V RANGE)

					LIMITS		
SYMBOL	PARAMETER	TEST CONDITIONS		Temp = -40°C to +85°C		+85°C	
					TYP ¹	MAX	1
VIK	Input clamp voltage	$V_{CC} = 2.3V; I_{IK} = -18mA$			-0.85	-1.2	V
V _{OH}	High-level output voltage	V _{CC} = 2.3V; I _{OH} = -8mA		1.7	2.5		V
V _{OL}	Low-level output voltage	V _{CC} = 2.3V; I _{OL} = 12mA			0.3	0.5	V
V _{RST}	Power-up output low voltage ⁷	V_{CC} = 2.7V; I_{O} = 1mA; V_{I} = V_{CC} or GND			0.2	0.55	V
		V _{CC} = 2.7V; V _I = GND	Control pins		0.1	±1	μA
		$V_{CC} = 2.7V; V_1 = 5.5V$	Control pins		0.1	10	
l	Input leakage current	$V_{CC} = 3.6V; V_{I} = 5.5V$			0.1	10	μA
		$V_{CC} = 3.6V; V_{I} = V_{CC}$	Data pins ⁴		0.5	1	
		$V_{CC} = 3.6V; V_{I} = 0$	1		0.1	-5	
I _{OFF}	Off current	$V_{CC} = 0V; V_{I} \text{ or } V_{O} = 0 \text{ to } 4.5V$			0.1	±100	μΑ
	Bus Hold current	$V_{CC} = 2.5V; V_1 = 0.7V$			100		μΑ
HOLD	D inputs ⁶	V _{CC} = 2.5V; V _I = 1.7V			-70		μΑ
I _{EX}	Current into an output in the High state when $V_O > V_{CC}$	$V_{O} = 5.5V; V_{CC} = 2.5V$			10	125	μΑ
I _{PU/PD}	Power up/down 3-State output current ³	$V_{CC} \le 1.2V$; $V_O = 0.5V$ to V_{CC} ; $V_I = GND$ OE/OE = Don't care) or V _{CC} ;		1	±100	μΑ
I _{OZH}	3-State output High current	$V_{CC} = 2.7V; V_{O} = 2.3V; V_{I} = V_{IL} \text{ or } V_{IH}$			0.5	5	μΑ
I _{OZL}	3-State output Low current	$V_{CC} = 2.7V; V_{O} = 0.5V; V_{I} = V_{IL} \text{ or } V_{IH}$			0.5	-5	μA
I _{CCH}		V_{CC} = 2.7V; Outputs High, V_{I} = GND or V	V _{CC} , I _{O =} 0		0.04	0.1	
I _{CCL}	Quiescent supply current	$V_{CC} = 2.7V$; Outputs Low, $V_I = GND$ or V_{CC} , $I_O = 0$			2.7	4.5	mA
I _{CCZ}	1	V_{CC} = 2.7V; Outputs Disabled; V_{I} = GND		0.04	0.1		
ΔI_{CC}	Additional supply current per input pin ²	V_{CC} = 2.3V to 2.7V; One input at V_{CC} -0. Other inputs at V_{CC} or GND	6V,		0.04	0.4	mA

NOTES:

1. All typical values are at $V_{CC} = 2.5V$ and $T_{amb} = 25^{\circ}C$. 2. This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND 3. This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From $V_{CC} = 1.2V$ to $V_{CC} = 2.5V \pm 0.2V$ a transition time of 100 μ sec is permitted. This parameter is valid for T_{amb} = 25°C only.

4. Unused pins at V_{CC} or GND. 5. I_{CCZ} is measured with outputs pulled up to V_{CC} or pulled down to ground.

6. Not guaranteed.

7. For valid test results, data must not be loaded into the flip-flops (or latches) after applying power.

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AC CHARACTERISTICS (2.5V $\pm\,0.2V$ RANGE)

GND = 0V, $t_R = t_F = 2.5$ ns, $C_L = 50$ pF, $R_L = 500\Omega$

				UNIT		
SYMBOL	PARAMETER	WAVEFORM	vo			
			MIN	ТҮР	МАХ	
f _{MAX}	Maximum clock frequency	1				MHz
t _{PLH} t _{PHL}	Propagation delay nCP to nQx	1	2.5 2.0	4.2 3.4	6.3 5.0	ns
t _{PHL}	Propagation delay nMR to nQx	2	2.0	3.4	4.6	ns
t _{PZH} t _{PZL}	Output enable time to High and Low level	4 5	3.0 2.0	4.8 3.2	7.6 5.2	ns
t _{PHZ} t _{PLZ}	Output disable time from High and Low level	4 5	2.5 2.0	4.4 3.3	6.7 5.2	ns

AC SETUP REQUIREMENTS (2.5V \pm 0.2V RANGE)

GND = 0V, t_R = t_F = 2.5ns, C_L = 50pF, R_L = 500 Ω

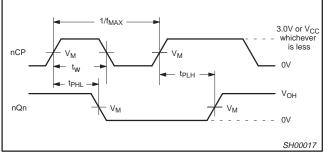
SYMBOL	PARAMETER	WAVEFORM	LIMITS T _{amb} = -40 to +85°C V _{CC} = +2.5V ±0.2V		UNIT
			t _s (H) t _s (L)	Setup time, High or Low nDx to nCP	3
t _h (H) t _h (L)	Hold time, High or Low nDx to nCP	3	0.1 0.1	-1.5 -0.6	ns
t _w (H) t _w (L)	nCP pulse width High or Low	1	2.0 3.0	0.8 2.1	ns
t _s (H) t _s (L)	Setup time, High or Low nCE to nCP	3	1.0 0.5	0.2 0.2	ns
t _h (H) t _h (L)	Hold time, High or Low nCE to nCP	3	1.0 1.0	0.2 0.1	ns
t _w (L)	nMR pulse width, Low	2	2.5	1.6	ns
t _{rec}	Recovery time nMR to nCP	2	2.3	1.7	ns

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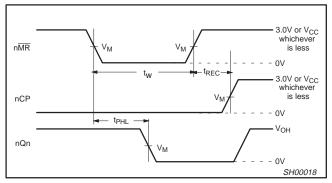
AC WAVEFORMS

For all waveforms, V_M = 1.5V or $V_{CC}/2$ whichever is less

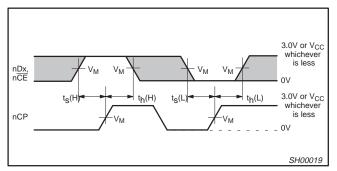
The shaded areas indicate when the input is permitted to change for predictable output performance.



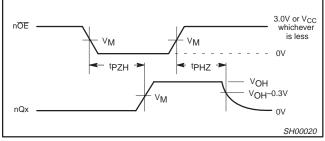
Waveform 1. Propagation Delay, Clock Input to Output, Clock Pulse Width, and Maximum Clock Frequency



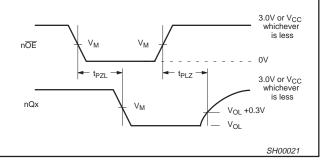
Waveform 2. Master Reset Pulse Width, Master Reset to Output Delay and Master Reset to Clock Recovery Time



Waveform 3. Data Setup and Hold Times



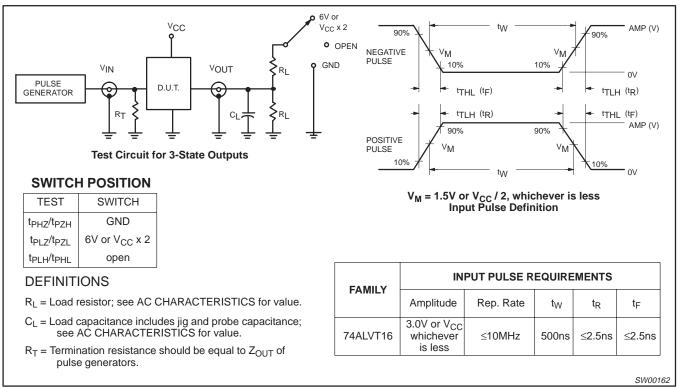
Waveform 4. 3-State Output Enable Time to High Level and Output Disable Time from High Level



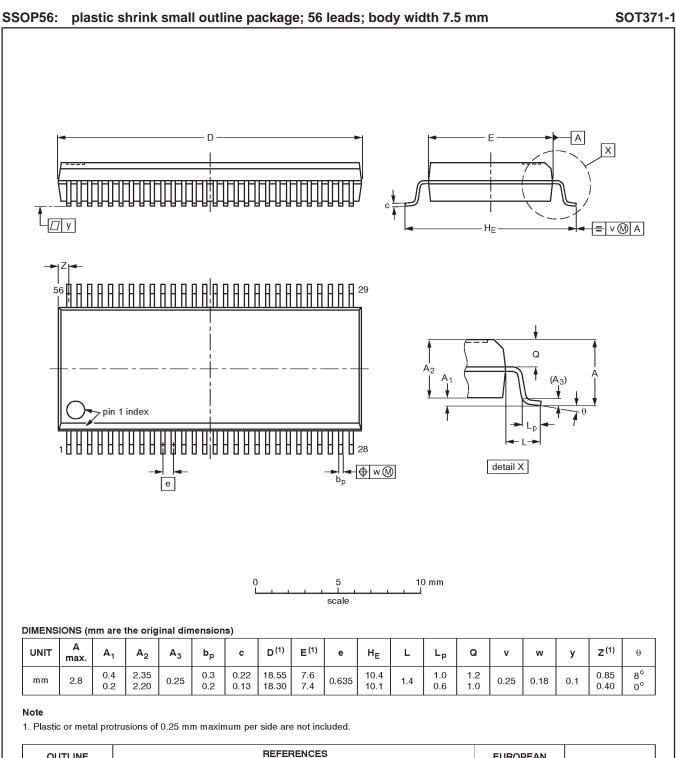
Waveform 5. 3-State Output Enable Time to Low Level and Output Disable Time from Low Level

74ALVT162823

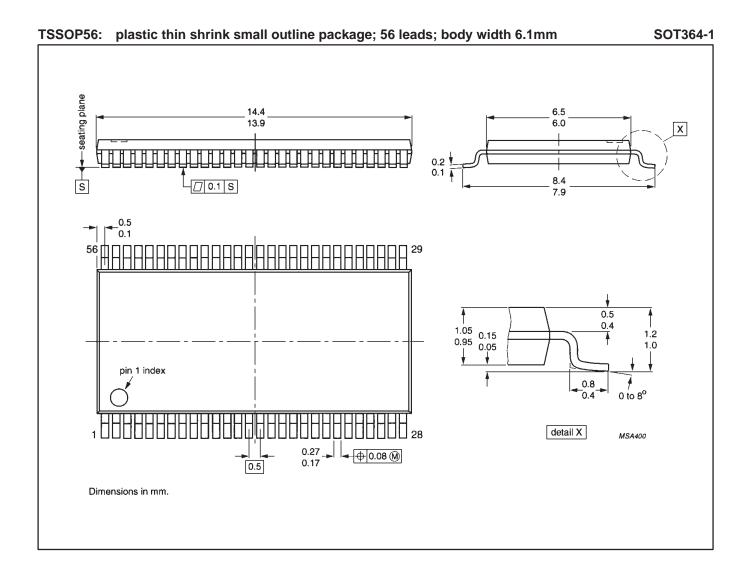
TEST CIRCUIT AND WAVEFORM



74ALVT162823



74ALVT162823



74ALVT162823

NOTES

74ALVT162823

Data sheet status

Data sheet status	Product status	Definition ^[1]	
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.	
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.	
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.	

[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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